



TPS22920 Ultra-Low On-Resistance, 4-A Integrated Load Switch with Controlled Turn-on

1 Features

- Input Voltage Range: 0.75-V to 3.6-V
- Integrated Load Switch
- Integrated Pass-FET $r_{DS(on)} = 2\text{ m}\Omega$ (typ) at 3.6-V
- Ultra-Low ON-Resistance
 - $r_{ON} = 5.3\text{-m}\Omega$ at 3.6-V
 - $r_{ON} = 5.4\text{-m}\Omega$ at 2.5-V
 - $r_{ON} = 5.5\text{-m}\Omega$ at 1.8-V
 - $r_{ON} = 5.8\text{-m}\Omega$ at 1.2-V
 - $r_{ON} = 6.1\text{-m}\Omega$ at 1.05-V
 - $r_{ON} = 7.3\text{-m}\Omega$ at 0.75-V
- Ultra Small CSP-8 package 0.9 mm × 1.9 mm, 0.5 mm pitch
- 4-A Maximum Continuous Switch Current
- Shutdown Current 5.5- μ A Max
- Low Threshold Control Input
- Controlled Slew-Rate to Avoid Inrush Current
- Quick Output Discharge Transistor
- ESD Performance Tested Per JESD 22
 - 4000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)

2 Applications

- Notebook / Netbook Computer
- Tablet PC
- PDAs / Smartphones
- GPS Navigation Devices
- MP3 Players

3 Description

The TPS22920 is a small, ultra-low r_{ON} load switch with controlled turn on. The device contains a N-channel MOSFET that can operate over an input voltage range of 0.75 V to 3.6 V and switch currents up to 4-A. An integrated charge pump biases the NMOS switch in order to achieve a minimum switch ON resistance (r_{ON}). The switch is controlled by an on/off input (ON), which is capable of interfacing directly with low-voltage control signals.

The TPS22920 has a 1250- Ω on-chip load resistor for quick output discharge when the switch is turned off which insures that the output is not left floating.

The TPS22920 has an internally controlled rise time in order to reduce inrush current. The TPS22920 features a rise time of 880 μ S at 3.6-V.

The TPS22920 is available in an ultra-small, space-saving 8-pin CSP package and is characterized for operation over the free-air temperature range of -40°C to 85°C .

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPS22920	DSBGA (8)	1.90 mm x 0.90 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Typical Application

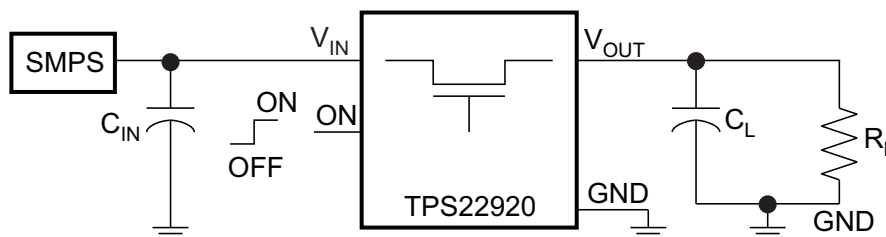


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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

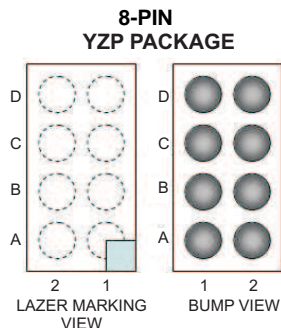
Changes from Revision A (July 2013) to Revision B	Page
<ul style="list-style-type: none"> Added <i>Pin Configuration and Functions</i> section, <i>Handling Rating</i> table, <i>Feature Description</i> section, <i>Device Functional Modes</i>, <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section 	1
Changes from Original (June 2011) to Revision A	Page
<ul style="list-style-type: none"> Updated swapped image issue. 	6

5 Device Options

	r_{ON} (typ) at 3.6 V	RISE TIME (typ) at 3.6V	QUICK OUTPUT DISCHARGE ⁽¹⁾	MAXIMUM OUTPUT CURRENT	ENABLE
TPS22920	5.3- mΩ	880 μS	Yes	4-A	Active High

(1) This feature discharges the output of the switch to ground through a 1250-Ω resistor, preventing the output from floating. See [Output Pull-Down](#).

6 Pin Configuration and Functions



Pin Functions

TPS22920 YZP	PIN NAME	I/O	DESCRIPTION
D1	GND	-	Ground
D2	ON	I	Switch control input, active high. Do not leave floating
A1, B1, C1	V_{OUT}	O	Switch output
A2, B2, C2	V_{IN}	I	Switch input, bypass this input with a ceramic capacitor to ground

Bump Assignments (YZP Package)

D	GND	ON
C	V_{OUT}	V_{IN}
B	V_{OUT}	V_{IN}
A	V_{OUT}	V_{IN}
	1	2

7 Specifications

7.1 Absolute Maximum Ratings⁽¹⁾

		MIN	MAX	UNIT
V _{IN}	Input voltage range	−0.3	4	V
V _{OUT}	Output voltage range		V _{IN} + 0.3	V
V _{ON}	Input voltage range	−0.3	4	V
I _{MAX}	Maximum Continuous Switch Current		4	A
I _{PLS}	Maximum Pulsed Switch Current, pulse <300 μs, 2% duty cycle		6	A
T _A	Operating free-air temperature range	−40	85	°C
T _J	Maximum junction temperature		125	°C
T _{LEAD}	Maximum lead temperature (10-s soldering time)		300	°C

- (1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress only, and functional operation of the device at these or any other conditions beyond those indicated under [Recommended Operating Conditions](#) is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 Handling Ratings

			MIN	MAX	UNIT
T _{stg}	Storage temperature range		−65	150	°C
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	−4000	4000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	−1000	1000	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

			MIN	MAX	UNIT
V _{IN}	Input voltage range		0.75	3.6	V
V _{OUT}	Output voltage range			V _{IN}	V
V _{IH}	High-level input voltage, ON	V _{IN} = 2.5 V to 3.6 V	1.2	3.6	V
		V _{IN} = 0.75 V to 2.49 V	0.9	3.6	V
V _{IL}	Low-level input voltage, ON	V _{IN} = 2.5 V to 3.6 V		0.6	V
		V _{IN} = 0.75 V to 2.49 V		0.4	V
C _{IN}	Input Capacitor		1 ⁽¹⁾		μF

- (1) See [Input Capacitor](#) section in Application Information.

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TPS22920	UNIT
		CS130P (8 PINS)	
θ _{JA}	Junction-to-ambient thermal resistance	130	°C/W
θ _{JCTop}	Junction-to-case (top) thermal resistance	54	
θ _{JB}	Junction-to-board thermal resistance	51	
ψ _{JT}	Junction-to-top characterization parameter	1	
ψ _{JB}	Junction-to-board characterization parameter	50	
θ _{JCbot}	Junction-to-case (bottom) thermal resistance	n/a	

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

7.5 Electrical Characteristics

Unless otherwise noted, $V_{IN} = 0.75\text{ V}$ to 3.6 V

PARAMETER		TEST CONDITIONS	T_A	MIN	TYP ⁽¹⁾	MAX	UNIT
I_{IN}	Quiescent Current	$V_{IN} = 3.6\text{ V}$	Full		68	160	μA
		$V_{IN} = 2.5\text{ V}$			40	70	
		$V_{IN} = 1.8\text{ V}$			25	350	μA
		$V_{IN} = 1.2\text{ V}$			103	200	
		$V_{IN} = 1.05\text{ V}$			78	110	μA
		$V_{IN} = 0.75\text{ V}$			37	70	
$I_{IN(Leak)}$	Off Supply Current (After Pull Down)	$V_{ON} = \text{GND}, V_{OUT} = 0$	Full			5.5	μA
r_{ON}	On-Resistance	$V_{IN} = 3.6\text{ V}, I_{OUT} = -200\text{ mA}$	25°C		5.3	8.8	$\text{m}\Omega$
			Full			9.8	
		$V_{IN} = 2.5\text{ V}, I_{OUT} = -200\text{ mA}$	25°C		5.4	8.9	$\text{m}\Omega$
			Full			9.9	
		$V_{IN} = 1.8\text{ V}, I_{OUT} = -200\text{ mA}$	25°C		5.5	9.1	$\text{m}\Omega$
			Full			10.1	
		$V_{IN} = 1.2\text{ V}, I_{OUT} = -200\text{ mA}$	25°C		5.8	9.4	$\text{m}\Omega$
			Full			10.4	
		$V_{IN} = 1.05\text{ V}, I_{OUT} = -200\text{ mA}$	25°C		6.1	9.7	$\text{m}\Omega$
			Full			10.8	
		$V_{IN} = 0.75\text{ V}, I_{OUT} = -200\text{ mA}$	25°C		7.3	11.0	$\text{m}\Omega$
			Full			12.4	
RPD	Output pull down resistance ⁽²⁾	$V_{IN} = 3.3\text{ V}, V_{ON} = 0, I_{OUT} = 3\text{ mA}$	Full		1250	1500	Ω
I_{ON}	ON input leakage current	$V_{ON} = 0.9\text{ V}$ to 3.6 V or GND	Full			0.1	μA

(1) Typical values are at $V_{IN} = 3.3\text{ V}$ and $T_A = 25^\circ\text{C}$.

(2) See [Output Pull-Down](#).

7.6 Switching Characteristics: $V_{IN} = 3.6\text{ V}$

Unless otherwise noted $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITION	MIN	TYP	MAX	UNIT
t_{ON}	Turn-ON time		970		μs
t_{OFF}	Turn-OFF time		3		
t_r	VOUT Rise time		880		
t_f	VOUT Fall time		2		

7.7 Switching Characteristics: $V_{IN} = 0.9\text{ V}$

$V_{IN} = 0.9\text{ V}, T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITION	MIN	TYP	MAX	UNIT
t_{ON}	Turn-ON time		840		μs
t_{OFF}	Turn-OFF time		16		
t_r	VOUT Rise time		470		
t_f	VOUT Fall time		5		

7.8 Typical Characteristics

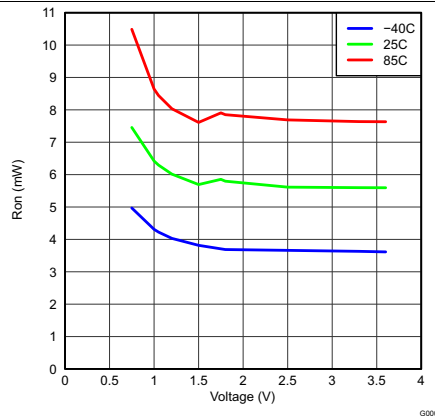


Figure 1. On-State Resistance vs Input Voltage

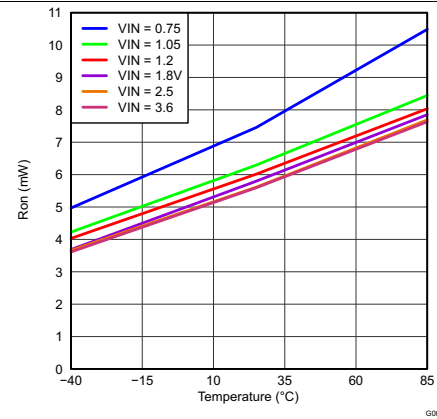


Figure 2. On-State Resistance vs Temperature

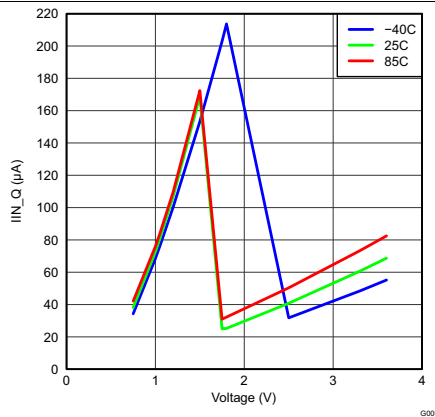


Figure 3. Input Current, Quiescent vs Input Voltage

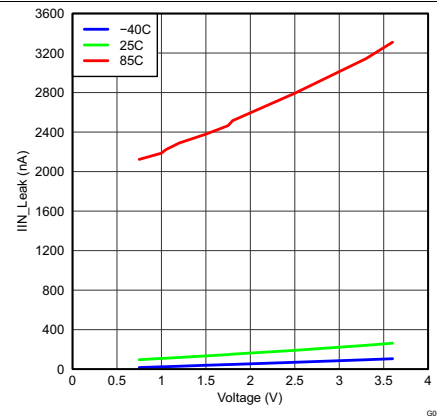


Figure 4. Input Current, Leak vs Input Voltage

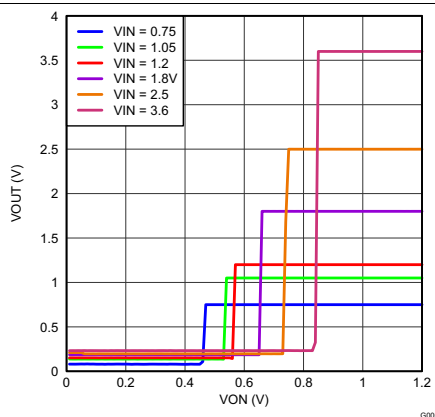


Figure 5. ON Input Threshold

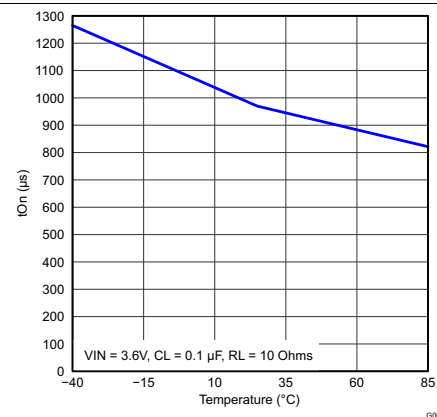


Figure 6. Turn-On Time vs Temperature

Typical Characteristics (continued)

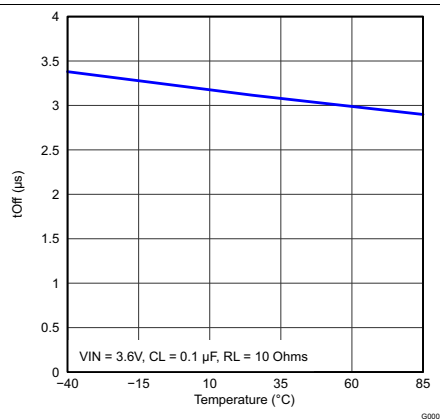


Figure 7. Turn-Off Time vs Temperature

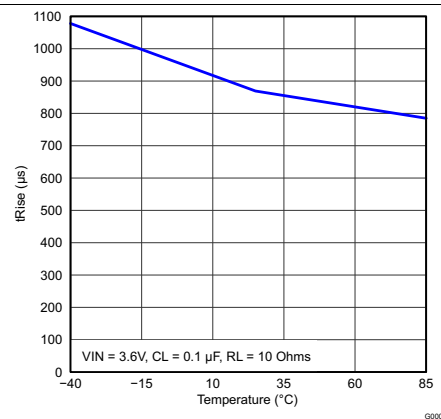


Figure 8. Rise Time vs Temperature

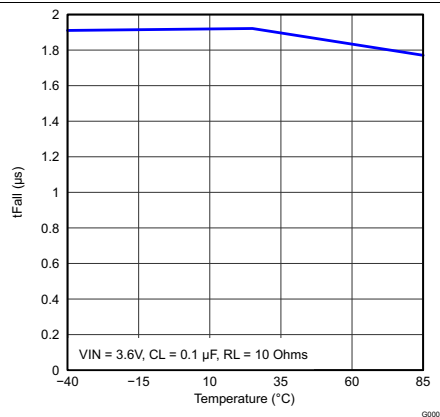


Figure 9. Fall Time vs Temperature

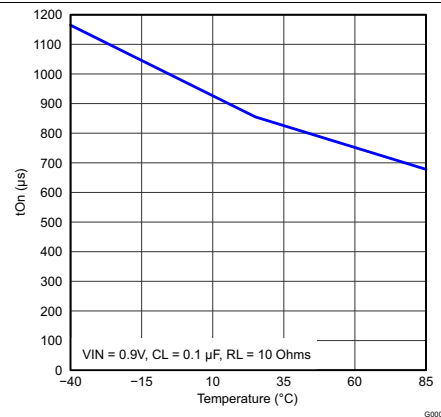


Figure 10. Turn-On Time vs Temperature

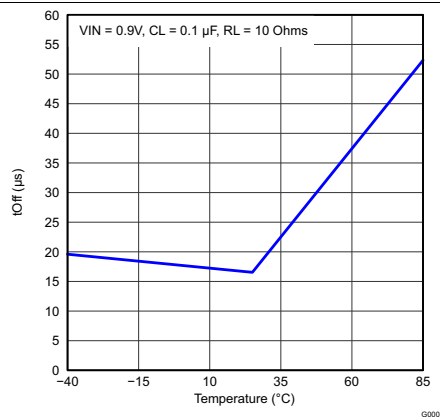


Figure 11. Turn-Off Time vs Temperature

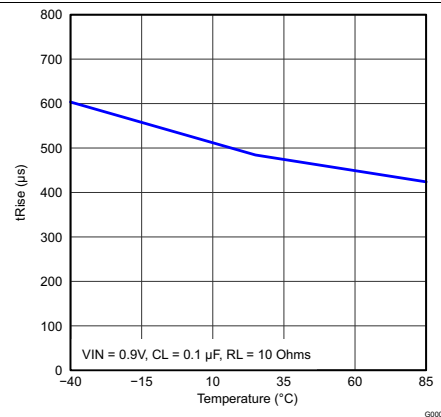


Figure 12. Rise Time vs Temperature

Typical Characteristics (continued)

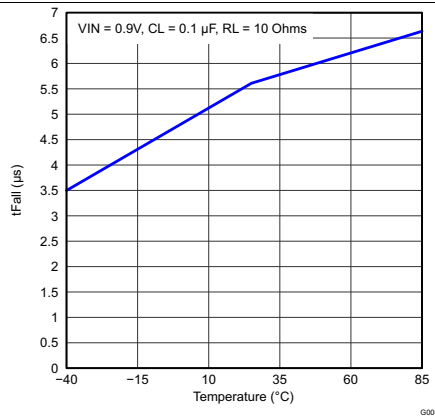


Figure 13. Fall Time vs Temperature

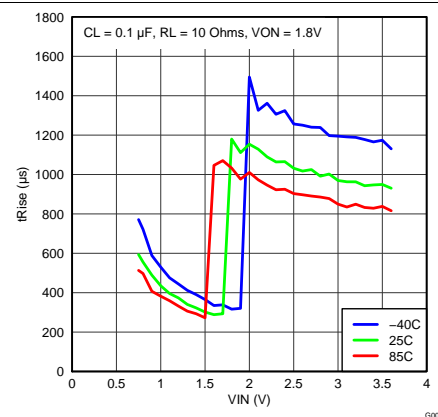


Figure 14. Rise Time vs Input Voltage

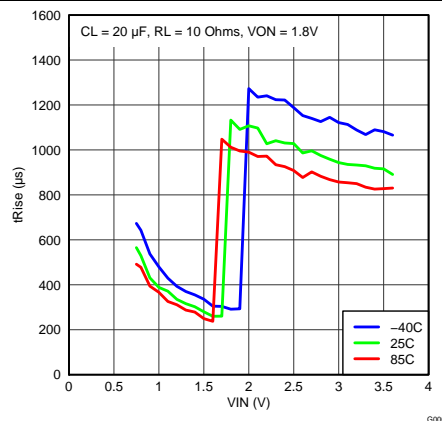


Figure 15. Rise Time vs Input Voltage

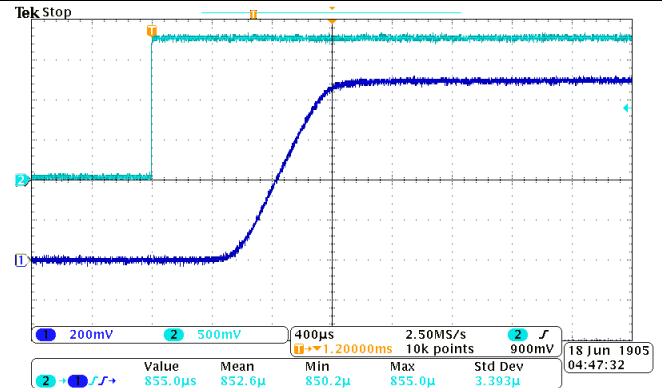


Figure 16. Turn-On Response VIN = 0.9 V, TA = 25°C, CIN = 1 μF, CL = 0.1 μF, RL = 10 ω

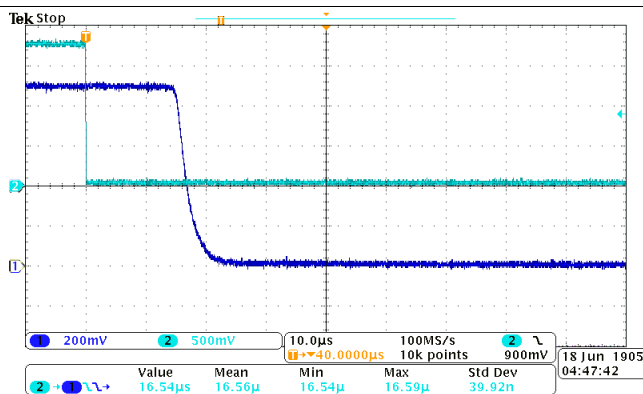


Figure 17. Turn-Off Response VIN = 0.9 V, TA = 25°C, CIN = 1 μF, CL = 0.1 μF, RL = 10 ω

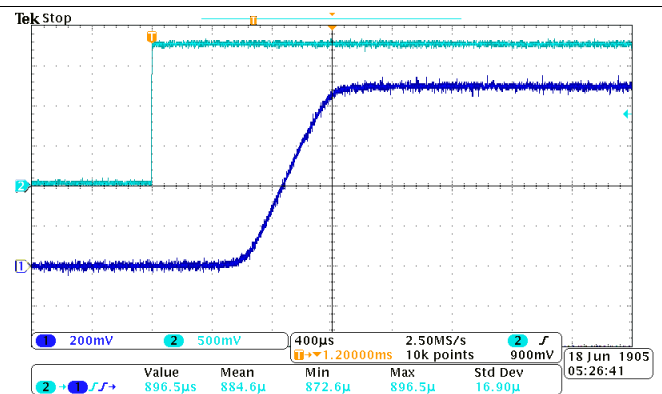


Figure 18. Turn-On Response VIN = 0.9 V, TA = 25°C, CIN = 47 μF, CL = 20 μF, RL = 10 ω

Typical Characteristics (continued)

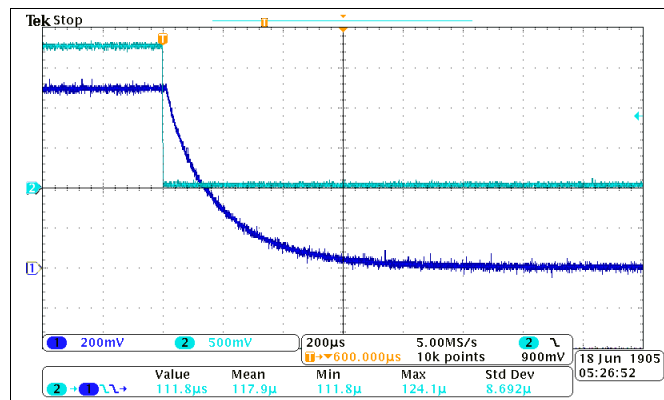


Figure 19. Turn-Off Response $V_{IN} = 0.9\text{ V}$, $T_A = 25^\circ\text{C}$, $C_{IN} = 47\text{ }\mu\text{F}$, $C_L = 20\text{ }\mu\text{F}$, $R_L = 10\text{ }\omega$

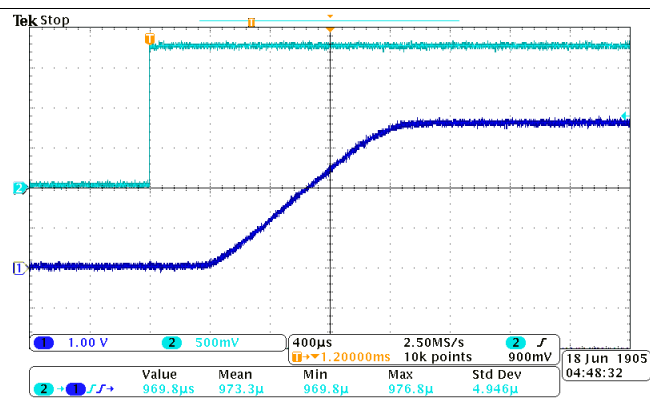


Figure 20. Turn-On Response $V_{IN} = 3.6\text{ V}$, $T_A = 25^\circ\text{C}$, $C_{IN} = 1\text{ }\mu\text{F}$, $C_L = 0.1\text{ }\mu\text{F}$, $R_L = 10\text{ }\omega$

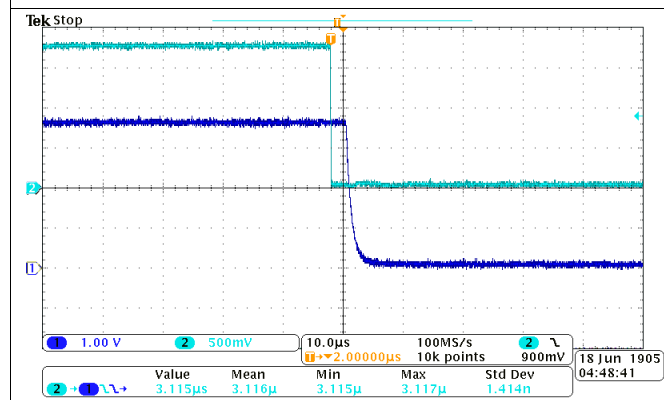


Figure 21. Turn-Off Response $V_{IN} = 3.6\text{ V}$, $T_A = 25^\circ\text{C}$, $C_{IN} = 1\text{ }\mu\text{F}$, $C_L = 0.1\text{ }\mu\text{F}$, $R_L = 10\text{ }\omega$

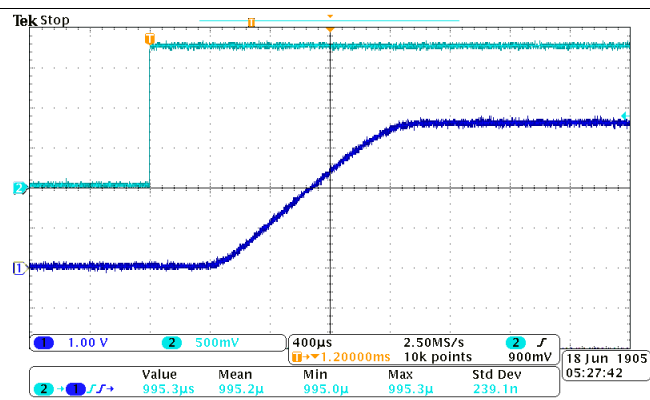


Figure 22. Turn-On Response $V_{IN} = 3.6\text{ V}$, $T_A = 25^\circ\text{C}$, $C_{IN} = 47\text{ }\mu\text{F}$, $C_L = 20\text{ }\mu\text{F}$, $R_L = 10\text{ }\omega$

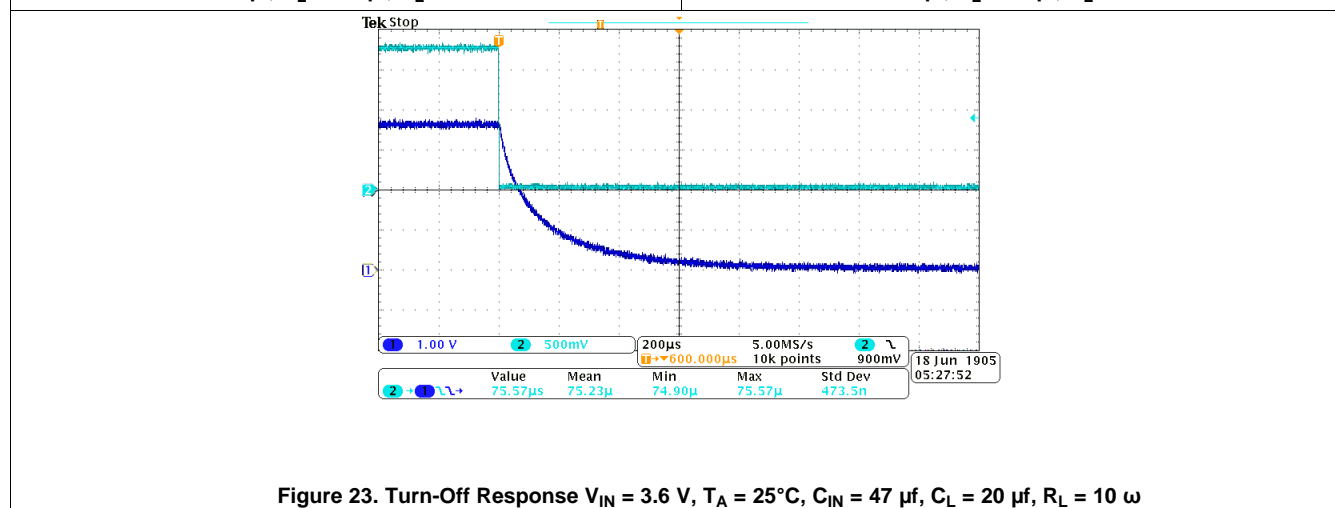
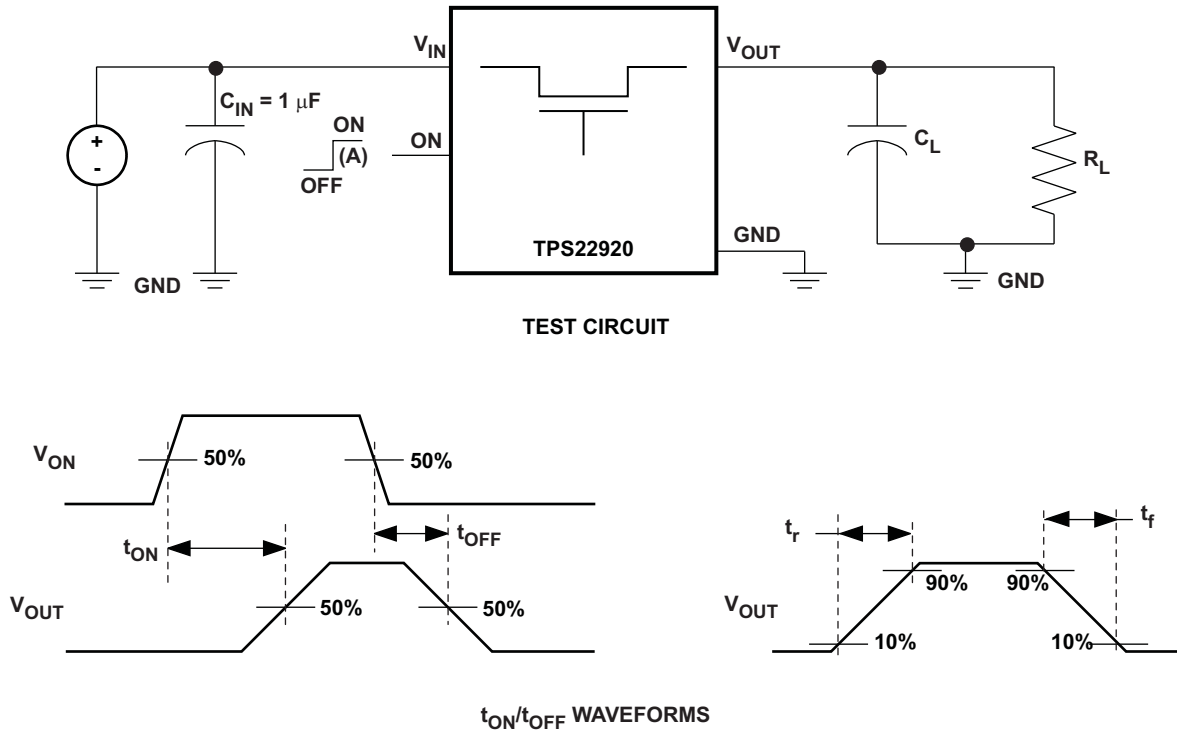


Figure 23. Turn-Off Response $V_{IN} = 3.6\text{ V}$, $T_A = 25^\circ\text{C}$, $C_{IN} = 47\text{ }\mu\text{F}$, $C_L = 20\text{ }\mu\text{F}$, $R_L = 10\text{ }\omega$

8 Parametric Measurement Information



(A) Rise and fall times of the control signal is 100 ns.

Figure 24. Test Circuit and T_{ON}/T_{OFF} Waveforms

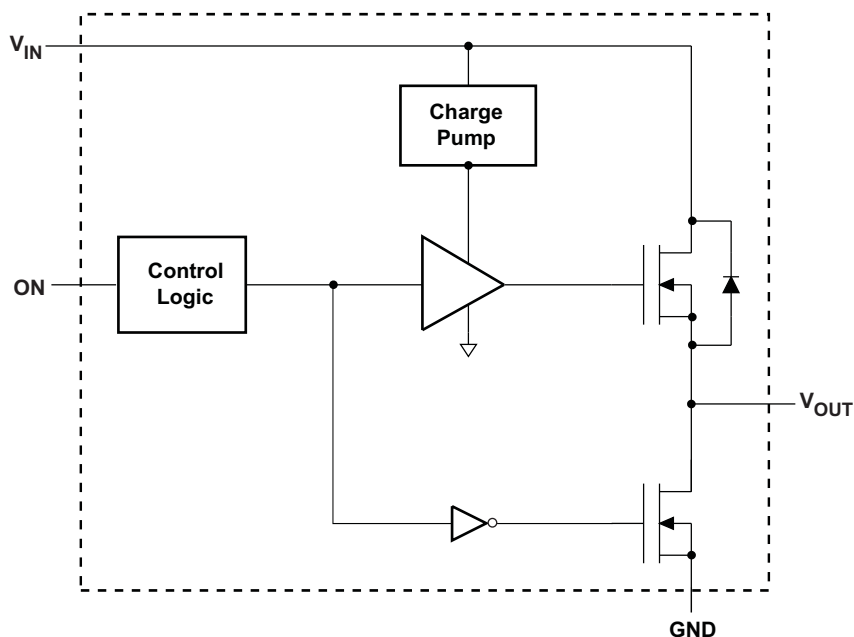
9 Detailed Description

9.1 Overview

The TPS22920 is a single channel, 4-A load switch in a small, space-saving CSP-8 package. This device implements a low resistance N-channel MOSFET with a controlled rise time for applications that need to limit the inrush current.

This device is also designed to have very low leakage current during off state. This prevents downstream circuits from pulling high standby current from the supply. Integrated control logic, driver, power supply, and output discharge FET eliminates the need for additional external components, which reduces solution size and bill of materials (BOM) count.

9.2 Functional Block Diagram



9.3 Feature Description

9.3.1 ON/OFF Control

The ON pin controls the state of the switch. Asserting ON high enables the switch. ON is active high and has a low threshold, making it capable of interfacing with low-voltage signals. The ON pin is compatible with standard GPIO logic threshold. It can be used with any microcontroller with 1.2-V, 1.8-V, 2.5-V or 3.3-V GPIOs.

9.3.2 Output Pull-Down

The output pulldown is active when the user is turning off the main pass FET. The pulldown discharges the output rail to approximately 10% of the rail, and then the output pulldown is automatically disconnected to optimize the shutdown current.

9.4 Device Functional Modes

ON	V_{IN} to V_{OUT}	V_{OUT} to GND ⁽¹⁾
L	OFF	ON
H	ON	OFF

(1) See [Output Pull-Down](#).

10 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

10.1.1 Input Capacitor

To limit the voltage drop on the input supply caused by transient inrush currents when the switch turns on into a discharged load capacitor or short-circuit, a capacitor needs to be placed between V_{IN} and GND. A 1- μ F ceramic capacitor, C_{IN} , placed close to the pins is usually sufficient. Higher values of C_{IN} can be used to further reduce the voltage drop.

10.1.2 Output Capacitor

Due to the integral body diode in the NMOS switch, a C_{IN} greater than C_L is highly recommended. A C_L greater than C_{IN} can cause V_{OUT} to exceed V_{IN} when the system supply is removed. This could result in current flow through the body diode from V_{OUT} to V_{IN} . A C_{IN} to C_L ratio of 10 to 1 is recommended for minimizing V_{IN} dip caused by inrush currents during startup.

10.2 Typical Application

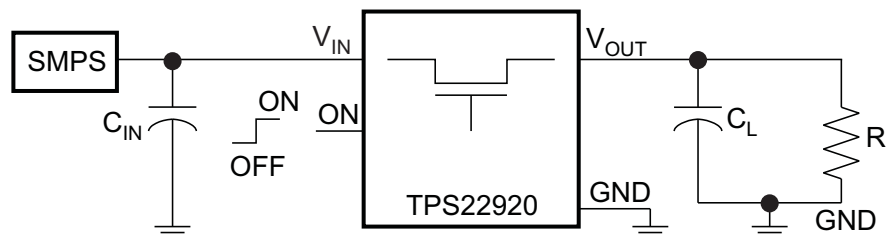


Figure 25. Typical Application Circuit

10.2.1 Design Requirements

DESIGN PARAMETER	EXAMPLE VALUE
V_{IN}	3.3 V
C_L	4.7 μ F
Maximum Acceptable Inrush Current	40 mA

10.2.2 Detailed Design Procedure

10.2.2.1 V_{IN} to V_{OUT} Voltage Drop

The V_{IN} to V_{OUT} voltage drop in the device is determined by the R_{ON} of the device and the load current. The R_{ON} of the device depends upon the V_{IN} condition of the device. Refer to the R_{ON} specification of the device in the Electrical Characteristics table of this datasheet. Once the R_{ON} of the device is determined based upon the V_{IN} conditions, use Equation 1 to calculate the V_{IN} to V_{OUT} voltage drop:

$$\Delta V = I_{LOAD} \times R_{ON}$$

where

- ΔV = Voltage drop from V_{IN} to V_{OUT}
- I_{LOAD} = Load current
- R_{ON} = On-resistance of the device for a specific V_{IN}

- An appropriate I_{LOAD} must be chosen such that the I_{MAX} specification of the device is not violated. (1)

10.2.2.2 Managing Inrush Current

When the switch is enabled, the output capacitors must be charged up from 0-V to V_{IN} . This charge arrives in the form of inrush current. Inrush current can be calculated using the following equation:

$$\text{Inrush Current} = C \times \frac{dv}{dt}$$

where

- C = Output capacitance
- $\frac{dv}{dt}$ = Output slew rate (2)

The TPS22920 offers a very slow controlled rise time for minimizing inrush current. This device can be selected based upon the maximum acceptable slew rate which can be calculated using the design requirements and the inrush current equation. An output capacitance of 4.7 μF will be used since the amount of inrush increases with output capacitance:

$$40\text{mA} = 4.7\mu\text{F} \times \frac{dv}{dt} \quad (3)$$

$$\frac{dv}{dt} = 8.5\text{V/ms} \quad (4)$$

To ensure an inrush current of less than 40 mA, a device with a slew rate less than 8.5 V/ms must be used.

The TPS22920 has a typical rise time of 880 μs at 3.3 V. This results in a slew rate of 3.75 V/ms which meets the above design requirements.

10.2.3 Application Curves

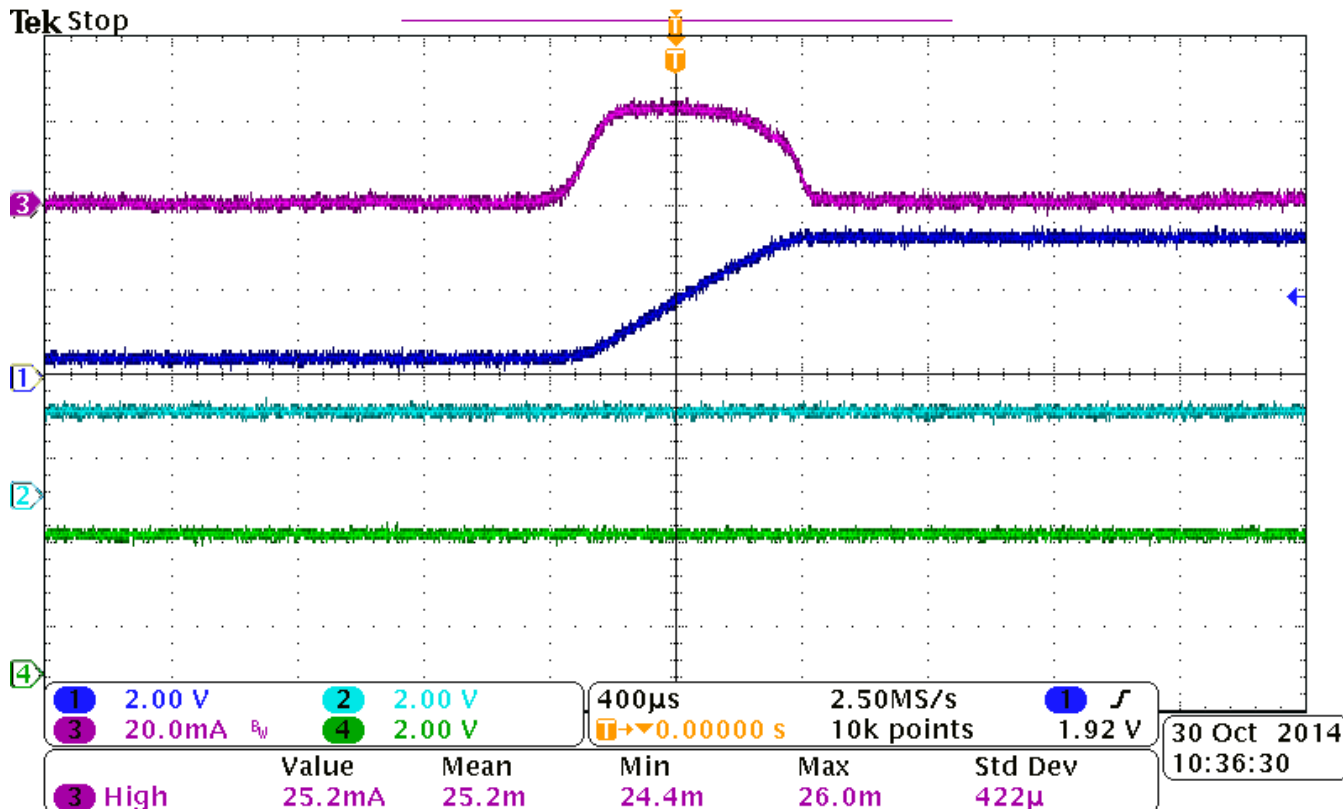


Figure 26. TPS22920 Inrush Current with 4.7- μF Output Capacitor

11 Power Supply Recommendations

The device is designed to operate with a V_{IN} range of 0.75 V to 3.6 V. This supply must be well regulated and placed as close to the device terminal as possible with the recommended 1 μ F bypass capacitor. If the supply is located more than a few inches from the device terminals, additional bulk capacitance may be required in addition to the ceramic bypass capacitors. If additional bulk capacitance is required, an electrolytic, tantalum, or ceramic capacitor of 10 μ F may be sufficient.

12 Layout

12.1 Layout Guidelines

For best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device terminal to minimize the effects that parasitic trace inductances may have on normal operation. Using wide traces for V_{IN} , V_{OUT} , and GND helps minimize the parasitic electrical effects along with minimizing the case to ambient thermal impedance.

12.2 Layout Example

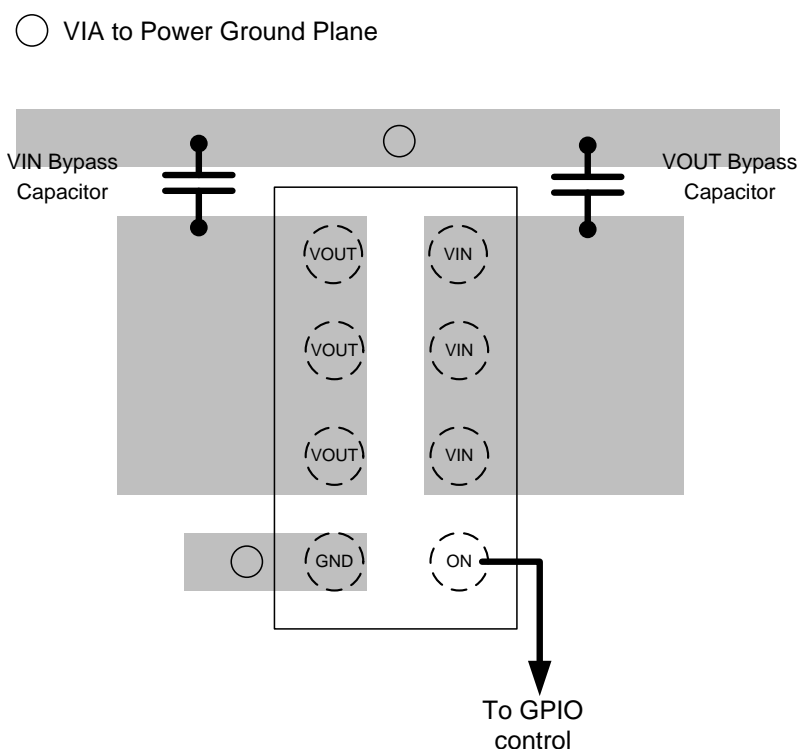


Figure 27. Layout Example

13 Device and Documentation Support

13.1 Trademarks

All trademarks are the property of their respective owners.

13.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.3 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS22920YZPR	ACTIVE	DSBGA	YZP	8	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	6Z	Samples
TPS22920YZPRB	ACTIVE	DSBGA	YZP	8	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	6Z S	Samples
TPS22920YZPT	ACTIVE	DSBGA	YZP	8	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	6Z	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS22920YZPR	DSBGA	YZP	8	3000	180.0	8.4	1.02	2.02	0.63	4.0	8.0	Q1
TPS22920YZPRB	DSBGA	YZP	8	3000	180.0	8.4	1.02	2.02	0.63	4.0	8.0	Q1
TPS22920YZPT	DSBGA	YZP	8	250	180.0	8.4	1.02	2.02	0.63	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS

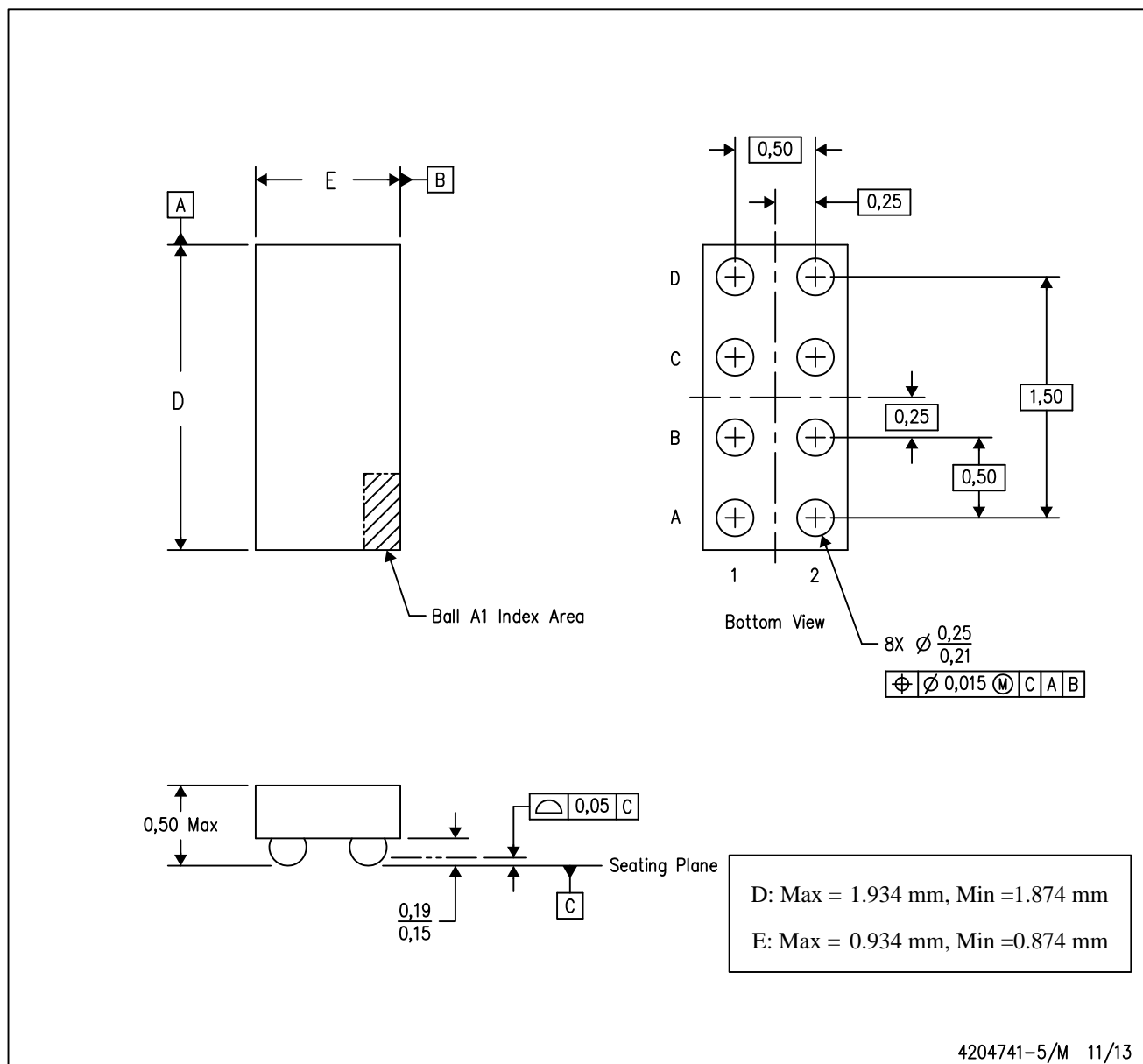


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS22920YZPR	DSBGA	YZP	8	3000	182.0	182.0	17.0
TPS22920YZPRB	DSBGA	YZP	8	3000	182.0	182.0	17.0
TPS22920YZPT	DSBGA	YZP	8	250	182.0	182.0	17.0

YZP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. NanoFree™ package configuration.

NanoFree is a trademark of Texas Instruments.

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➤ Sales :

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

➤ Customer Service :

Email service@ameya360.com

➤ Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com